

Component	RM1	Rmtop	Cdecap	Rdecap	CGP	CGN	ρ -sub
Description	Metal 1 resistance	Metal top resistance	Power decoupling capacitance	Power decoupling resistance	Equivalent PMOS gate capacitance	Equivalent NMOS gate capacitance	Substrate resistivity
Dual-well	$26\ \Omega$	$5\ \Omega$	$2.25\ fF$	$2\ \Omega$	$35.2\ fF$	$25.2\ fF$	$0.01\ \Omega.m$
Triple-well	$26\ \Omega$	$5\ \Omega$	$2.25\ fF$	$2\ \Omega$	$35.2\ fF$	$25.2\ fF$	$0.01\ \Omega.m$
Component	RP	RN	CNW	RC-GND	RC-VDD	RNW	RPW
Description	PMOS equivalent resistance	NMOS equivalent resistance	Diode capacitance	GND to substrate access resistance	access resistance	N-well access resistance	access resistance
Dual-well	$9.57\ \Omega$	$5.3\ \Omega$	$20\ fF$	$3.1\ k\Omega$	$3.1\ k\Omega$	n/a	n/a
Triple-well	$9.57\ \Omega$	$5.3\ \Omega$	$20\ fF$	n/a	n/a	$3.1\ k\Omega$	$3.1\ k\Omega$